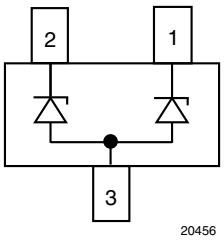
Small Signal Zener Diodes, Dual



FEATURES

- Dual silicon planar Zener diodes, common anode
- The Zener voltages are graded according to the international E24 standard. Standard Zener voltage tolerance is ± 5 %, indicated by the “C” in the ordering code. Replace “C” with “B” for 2 % tolerance.
- The parameters are valid for both diodes in one case. ΔV_Z and ΔR_{zj} of the two diodes in one case is ≤ 5 %
- AEC-Q101 qualified
- ESD capability according to AEC-Q101:
  Human body model > 8 kV
  Machine model > 800 V
- Base P/N-G3 - green, commercial grade
- Base P/N-HG3 - green, AEC-Q101 qualified (part number available on request)
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

Pb-free

e3

RoHS COMPLIANT

HALOGEN FREE GREEN (5-2008)

PRIMARY CHARACTERISTICS

PARAMETER	VALUE	UNIT
V_Z range nom.	2.7 to 51	V
Test current I_{ZT}	5	mA
V_Z specification	Pulse current	
Int. construction	Dual common anode	

ORDERING INFORMATION

DEVICE NAME	ORDERING CODE	TAPED UNITS PER REEL	MINIMUM ORDER QUANTITY
AZ23-G-series	AZ23C2V7-G3-08 to AZ23C51-G3-08	3000 (8 mm tape on 7" reel)	15 000
	AZ23B2V7-G3-08 to AZ23B51-G3-08		
	AZ23C2V7-G3-18 to AZ23C51-G3-18	10 000 (8 mm tape on 13" reel)	10 000
	AZ23B2V7-G3-18 to AZ23B51-G3-18		

PACKAGE

PACKAGE NAME	WEIGHT	MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS
SOT-23	8.1 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals

ABSOLUTE MAXIMUM RATINGS (T_{amb} = 25 °C, unless otherwise specified)

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Power dissipation	Device on fiberglass substrate, see layout on page 6	P_{tot}	300	mW
Thermal resistance, junction to ambient air	Device on fiberglass substrate, see layout on page 6	R_{thJA}	420	K/W
Junction temperature		T_j	150	°C
Storage temperature range		T_{stg}	-65 to +150	°C
Zener current		I_Z	P_{tot}/V_Z	mA
Operating temperature range		T_{op}	-55 to +150	°C

ELECTRICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

PART NUMBER	MARKING CODE	ZENER VOLTAGE RANGE (1)			TEST CURRENT		REVERSE VOLTAGE		DYNAMIC RESISTANCE		TEMPERATURE COEFFICIENT OF ZENER VOLTAGE	
		V_Z at I_{ZT1}			I_{ZT1}	I_{ZT2}	V_R at I_R		Z_Z at I_{ZT1}	Z_{ZK} at I_{ZT2}	α_{VZ} at I_{ZT}	
		V			mA		V	nA	Ω		10^{-4}/°C	
		MIN.	NOM.	MAX.							MIN.	MAX.
AZ23C2V7-G	D41	2.5	2.7	2.9	5	1	-	-	75 (< 83)	< 500	-9	-4
AZ23C3V0-G	D42	2.8	3.0	3.2	5	1	-	-	80 (< 95)	< 500	-9	-3
AZ23C3V3-G	D43	3.1	3.3	3.5	5	1	-	-	80 (< 95)	< 500	-8	-3
AZ23C3V6-G	D44	3.4	3.6	3.8	5	1	-	-	80 (< 95)	< 500	-8	-3
AZ23C3V9-G	D45	3.7	3.9	4.1	5	1	-	-	80 (< 95)	< 500	-7	-3
AZ23C4V3-G	D46	4	4.3	4.6	5	1	-	-	80 (< 95)	< 500	-6	-1
AZ23C4V7-G	D47	4.4	4.7	5	5	1	-	-	70 (< 78)	< 500	-5	2
AZ23C5V1-G	D48	4.8	5.1	5.4	5	1	> 0.8	100	30 (< 60)	< 480	-3	4
AZ23C5V6-G	D49	5.2	5.6	6	5	1	> 1	100	10 (< 40)	< 400	-2	6
AZ23C6V2-G	D50	5.8	6.2	6.6	5	1	> 2	100	4.8 (< 10)	< 200	-1	7
AZ23C6V8-G	D51	6.4	6.8	7.2	5	1	> 3	100	4.5 (< 8)	< 150	2	7
AZ23C7V5-G	D52	7	7.5	7.9	5	1	> 5	100	4 (< 7)	< 50	3	7
AZ23C8V2-G	D53	7.7	8.2	8.7	5	1	> 6	100	4.5 (< 7)	< 50	4	7
AZ23C9V1-G	D54	8.5	9.1	9.6	5	1	> 7	100	4.8 (< 10)	< 50	5	8
AZ23C10-G	D55	9.4	10	10.6	5	1	> 7.5	100	5.2 (< 15)	< 70	5	8
AZ23C11-G	D56	10.4	11	11.6	5	1	> 8.5	100	6 (< 20)	< 70	5	9
AZ23C12-G	D57	11.4	12	12.7	5	1	> 9	100	7 (< 20)	< 90	6	9
AZ23C13-G	D58	12.4	13	14.1	5	1	> 10	100	9 (< 25)	< 110	7	9
AZ23C15-G	D59	13.8	15	15.6	5	1	> 11	100	11 (< 30)	< 110	7	9
AZ23C16-G	D60	15.3	16	17.1	5	1	> 12	100	13 (< 40)	< 170	8	9.5
AZ23C18-G	D61	16.8	18	19.1	5	1	> 14	100	18 (< 50)	< 170	8	9.5
AZ23C20-G	D62	18.8	20	21.2	5	1	> 15	100	20 (< 50)	< 220	8	10
AZ23C22-G	D63	20.8	22	23.3	5	1	> 17	100	25 (< 55)	< 220	8	10
AZ23C24-G	D64	22.8	24	25.6	5	1	> 18	100	28 (< 80)	< 220	8	10
AZ23C27-G	D65	25.1	27	28.9	5	1	> 20	100	30 (< 80)	< 250	8	10
AZ23C30-G	D66	28	30	32	5	1	> 22.5	100	35 (< 80)	< 250	8	10
AZ23C33-G	D67	31	33	35	5	1	> 25	100	40 (< 80)	< 250	8	10
AZ23C36-G	D68	34	36	38	5	1	> 27	100	40 (< 90)	< 250	8	10
AZ23C39-G	D69	37	39	41	5	1	> 29	100	50 (< 90)	< 300	10	12
AZ23C43-G	D70	40	43	46	5	1	> 32	100	60 (< 100)	< 700	10	12
AZ23C47-G	D71	44	47	50	5	1	> 35	100	70 (< 100)	< 750	10	12
AZ23C51-G	D72	48	51	50	5	1	> 38	100	70 (< 100)	< 750	10	12

Note

(1) Tested with pulses t_p = 5 ms

ELECTRICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

PART NUMBER	MARKING CODE	ZENER VOLTAGE RANGE (1)			TEST CURRENT		REVERSE VOLTAGE		DYNAMIC RESISTANCE		TEMPERATURE COEFFICIENT OF ZENER VOLTAGE	
		V_Z at I_{ZT1}			I_{ZT1}	I_{ZT2}	V_R at I_R		Z_Z at I_{ZT1}	Z_{ZK} at I_{ZT2}	α_{VZ} at I_{ZT}	
		V			mA		V	nA	Ω		10^{-4}/°C	
		MIN.	NOM.	MAX.							MIN.	MAX.
AZ23B2V7-G	D41	2.65	2.7	2.75	5	1	-	-	75 (< 83)	< 500	-9	-4
AZ23B3V0-G	D42	2.94	3.0	3.06	5	1	-	-	80 (< 95)	< 500	-9	-3
AZ23B3V3-G	D43	3.23	3.3	3.37	5	1	-	-	80 (< 95)	< 500	-8	-3
AZ23B3V6-G	D44	3.53	3.6	3.67	5	1	-	-	80 (< 95)	< 500	-8	-3
AZ23B3V9-G	D45	3.82	3.9	3.98	5	1	-	-	80 (< 95)	< 500	-7	-3
AZ23B4V3-G	D46	4.21	4.3	4.39	5	1	-	-	80 (< 95)	< 500	-6	-1
AZ23B4V7-G	D47	4.61	4.7	4.79	5	1	-	-	70 (< 78)	< 500	-5	2
AZ23B5V1-G	D48	5	5.1	5.2	5	1	> 0.8	100	30 (< 60)	< 480	-3	4
AZ23B5V6-G	D49	5.49	5.6	5.71	5	1	> 1	100	10 (< 40)	< 400	-2	6
AZ23B6V2-G	D50	6.08	6.2	6.32	5	1	> 2	100	4.8 (< 10)	< 200	-1	7
AZ23B6V8-G	D51	6.66	6.8	6.94	5	1	> 3	100	4.5 (< 8)	< 150	2	7
AZ23B7V5-G	D52	7.35	7.5	7.65	5	1	> 5	100	4 (< 7)	< 50	3	7
AZ23B8V2-G	D53	8.04	8.2	8.36	5	1	> 6	100	4.5 (< 7)	< 50	4	7
AZ23B9V1-G	D54	8.92	9.1	9.28	5	1	> 7	100	4.8 (< 10)	< 50	5	8
AZ23B10-G	D55	9.8	10	10.2	5	1	> 7.5	100	5.2 (< 15)	< 70	5	8
AZ23B11-G	D56	10.8	11	11.2	5	1	> 8.5	100	6 (< 20)	< 70	5	9
AZ23B12-G	D57	11.8	12	12.2	5	1	> 9	100	7 (< 20)	< 90	6	9
AZ23B13-G	D58	12.7	13	13.3	5	1	> 10	100	9 (< 25)	< 110	7	9
AZ23B15-G	D59	14.7	15	15.3	5	1	> 11	100	11 (< 30)	< 110	7	9
AZ23B16-G	D60	15.7	16	16.3	5	1	> 12	100	13 (< 40)	< 170	8	0.5
AZ23B18-G	D61	17.6	18	18.4	5	1	> 14	100	18 (< 50)	< 170	8	0.5
AZ23B20-G	D62	19.6	20	20.4	5	1	> 15	100	20 (< 50)	< 220	8	10
AZ23B22-G	D63	21.6	22	22.4	5	1	> 17	100	25 (< 55)	< 220	8	10
AZ23B24-G	D64	23.5	24	24.5	5	1	> 18	100	28 (< 80)	< 220	8	10
AZ23B27-G	D65	26.5	27	27.5	5	1	> 20	100	30 (< 80)	< 250	8	10
AZ23B30-G	D66	29.4	30	30.6	5	1	> 22.5	100	35 (< 80)	< 250	8	10
AZ23B33-G	D67	32.3	33	33.7	5	1	> 25	100	40 (< 80)	< 250	8	10
AZ23B36-G	D68	35.3	36	36.7	5	1	> 27	100	40 (< 90)	< 250	8	10
AZ23B39-G	D69	38.2	39	39.8	5	1	> 29	100	50 (< 90)	< 300	10	12
AZ23B43-G	D70	42.1	43	43.9	5	1	> 32	100	60 (< 100)	< 700	10	12
AZ23B47-G	D71	46.1	47	47.9	5	1	> 35	100	70 (< 100)	< 750	10	12
AZ23B51-G	D72	50	51	52	5	1	> 38	100	70 (< 100)	< 750	10	12

Note

(1) Tested with pulses t_p = 5 ms

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

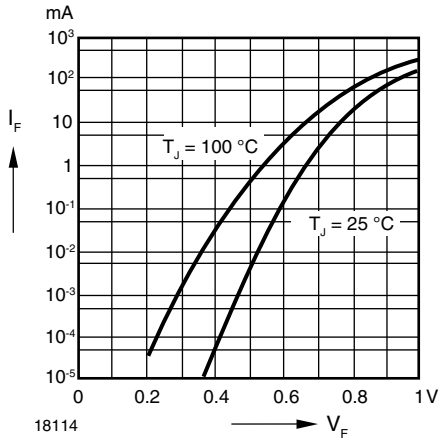


Fig. 1 - Forward Characteristics

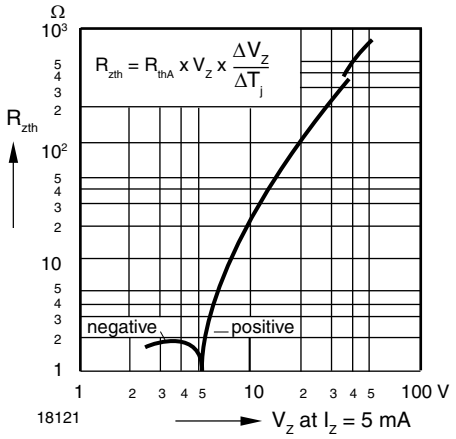


Fig. 4 - Thermal Differential Resistance vs. Zener Voltage

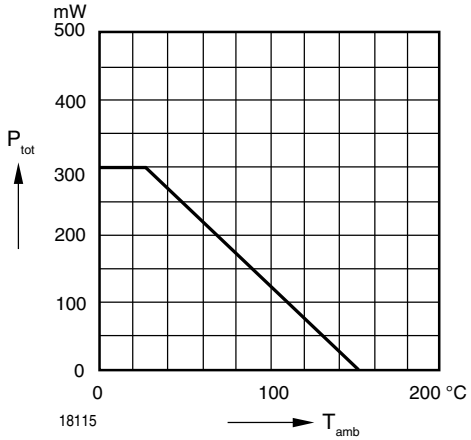


Fig. 2 - Admissible Power Dissipation vs. Ambient Temperature

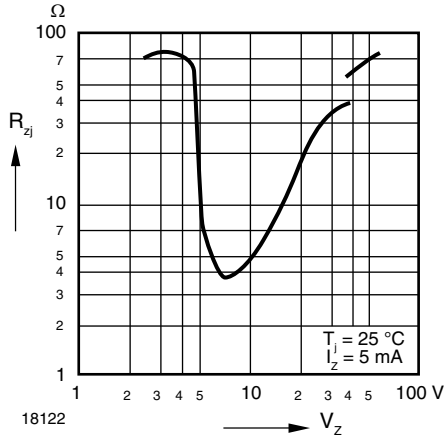


Fig. 5 - Dynamic Resistance vs. Zener Voltage

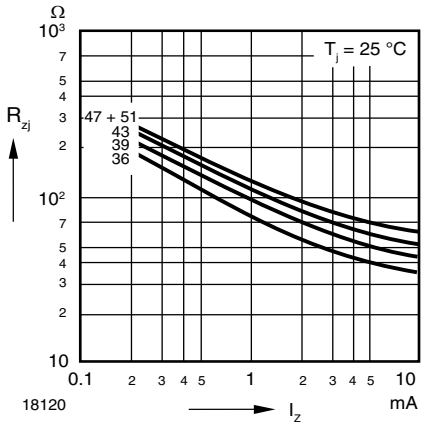


Fig. 3 - Dynamic Resistance vs. Zener Current

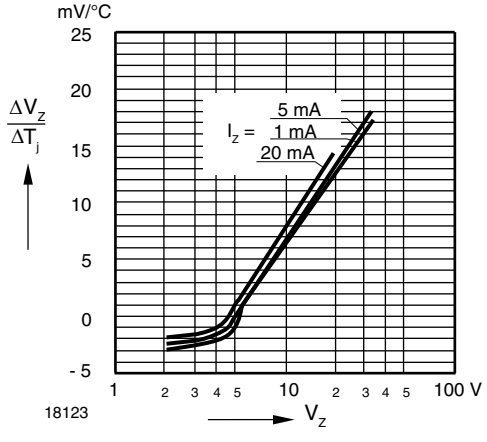


Fig. 6 - Temperature Dependence of Zener Voltage vs. Zener Voltage

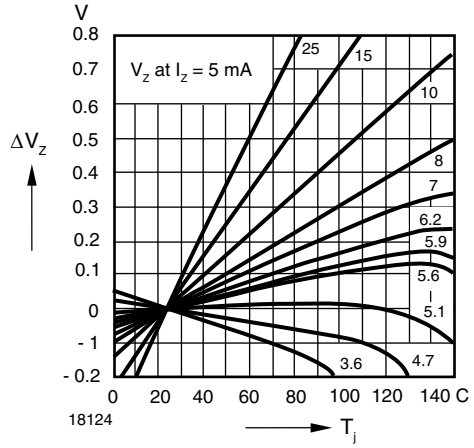


Fig. 7 - Change of Zener Voltage vs. Junction Temperature

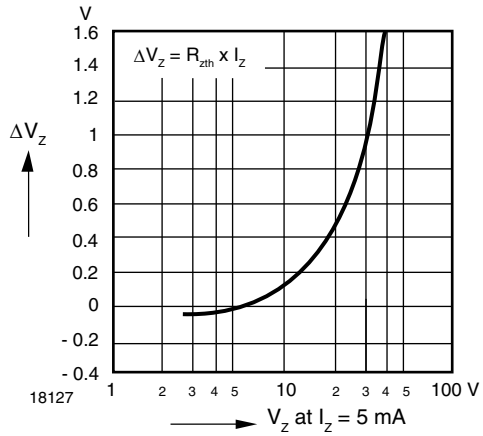


Fig. 10 - Change of Zener Voltage from Turn-on up to the Point of Thermal Equilibrium vs. Zener Voltage

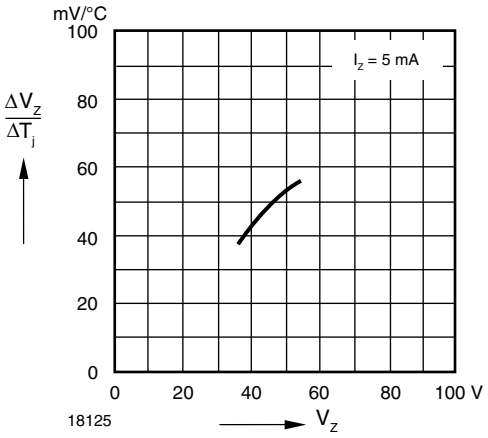


Fig. 8 - Temperature Dependence of Zener Voltage vs. Zener Voltage

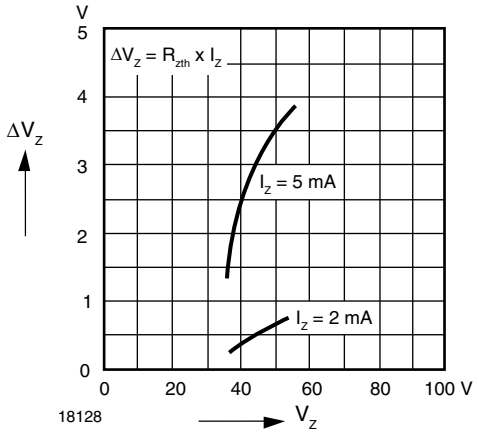


Fig. 11 - Change of Zener Voltage from Turn-on up to the Point of Thermal Equilibrium vs. Zener Voltage

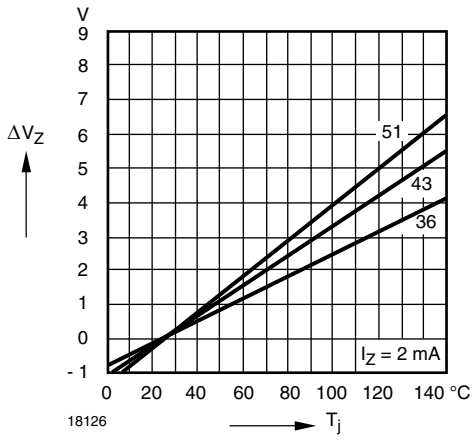


Fig. 9 - Change of Zener Voltage vs. Junction Temperature

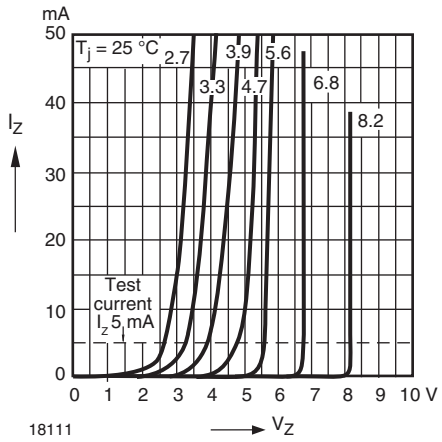


Fig. 12 - Breakdown Characteristics

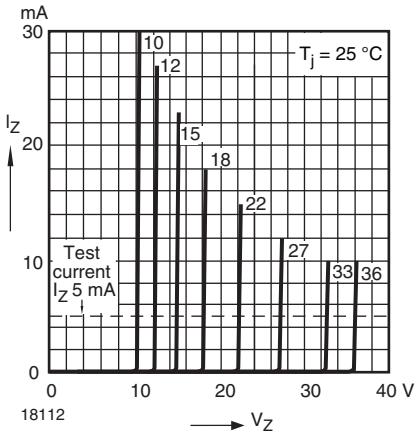


Fig. 13 - Breakdown Characteristics

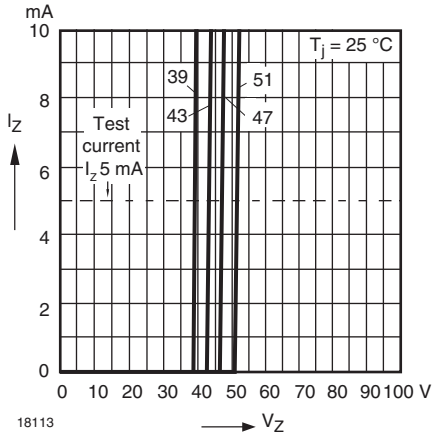
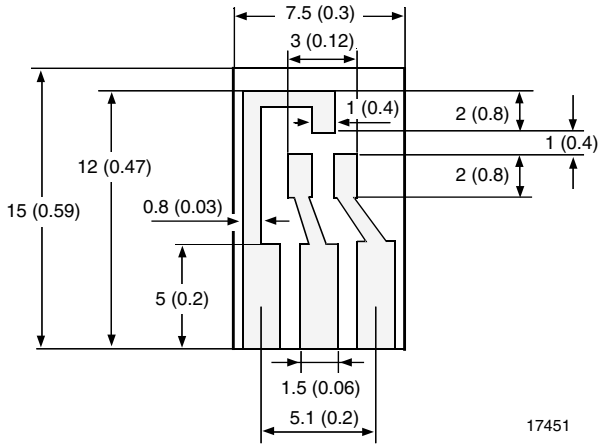


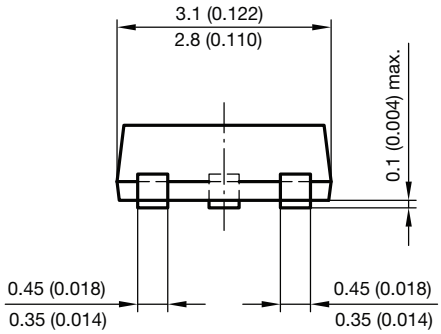
Fig. 14 - Breakdown Characteristics

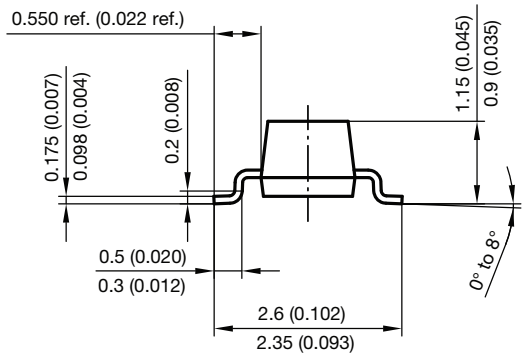
LAYOUT FOR R_{thJA} TEST

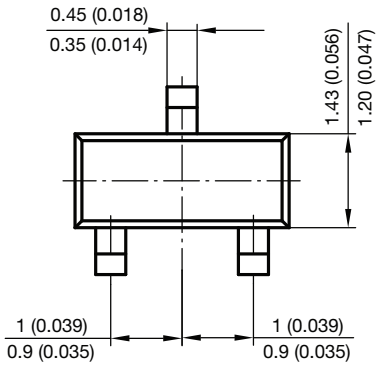
Thickness: fiberglass 0.059" (1.5 mm)
Copper leads 0.012" (0.3 mm)



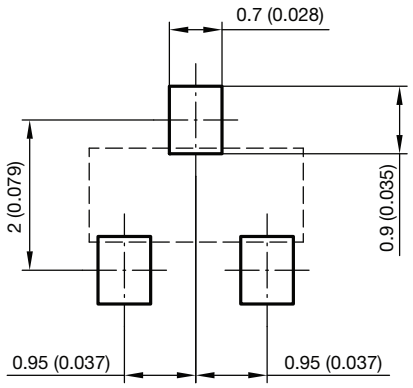
PACKAGE DIMENSIONS in millimeters (inches): **SOT-23**







Foot print recommendation:



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Rev. 8 - Date: 23.Sept.2009
17418

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Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

OCEAN CHIPS
Океан Электроники
Поставка электронных компонентов

Компания «Океан Электроники» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Поставка оригинальных импортных электронных компонентов напрямую с производств Америки, Европы и Азии, а так же с крупнейших складов мира;
- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «**JONHON**», а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «**FORSTAR**».

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(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).

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Телефон: 8 (812) 309-75-97 (многоканальный)
Факс: 8 (812) 320-03-32
Электронная почта: ocean@oceanchips.ru
Web: http://oceanchips.ru/
Адрес: 198099, г. Санкт-Петербург, ул. Калинина, д. 2, корп. 4, лит. А